

TOSHIBA Transistor Silicon-Germanium NPN Epitaxial Planer Type

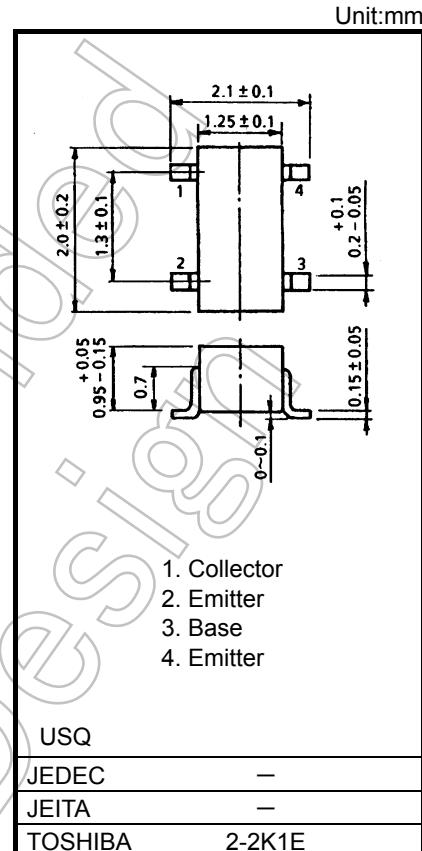
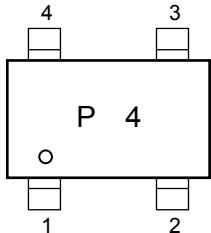
MT4S301U

○ UHF-SHF Low Noise Amplifier Application

FEATURES

- Low Noise Figure : $NF=0.57\text{dB}(\text{Typ.})$ (@ $f=2\text{GHz}$)
- High Gain : $|S_{21}|^2=18.1\text{dB}(\text{Typ.})$ (@ $f=2\text{GHz}$)
- 2 kV ESD robustness (HBM) due to integrated protection circuits

Marking



Weight: 6 mg (Typ.)

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Characteristics	Symbol	Rating	Unit
Collector-Base voltage	V_{CBO}	6	V
Collector-Emitter voltage	V_{CEO}	4	V
Collector-Current	I_C	35	mA
Base-Current	I_B	10	mA
Collector Power dissipation	P_C	100	mW
Collector Power dissipation	$P_C(\text{Note1})$	250	mW
Junction temperature	T_J	150	°C
Storage temperature Range	T_{stg}	-55~150	°C

Note1 : The device is mounted on a FR4 board (20 mm x 25 mm x 1.55 mm (t))

Note2: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Microwave Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Transition Frequency	f _T	V _{CE} =3V, I _C =15mA	23	27.5	—	GHz
Insertion Gain	S _{21e} ² (1)	V _{CE} =3V, I _C =15mA,f=2GHz	15.5	18.1	—	dB
	S _{21e} ² (2)	V _{CE} =3V, I _C =15mA,f=5.8GHz	9.5	11.5	—	dB
Noise Figure	NF(1)	V _{CE} =3V, I _C =7mA, f=2GHz	—	0.57	0.7	dB
	NF(2)	V _{CE} =3V, I _C =7mA,f=5.8GH	—	1.51	—	dB

Electrical Characteristics (Ta = 25°C)

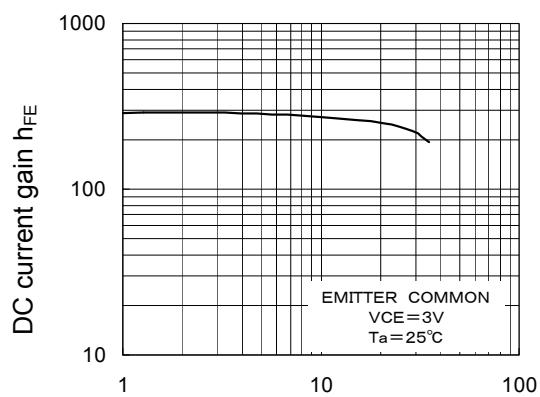
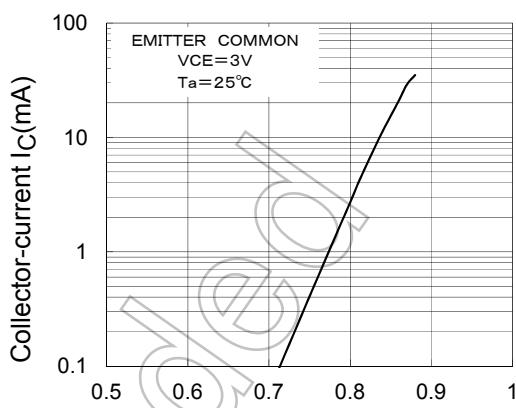
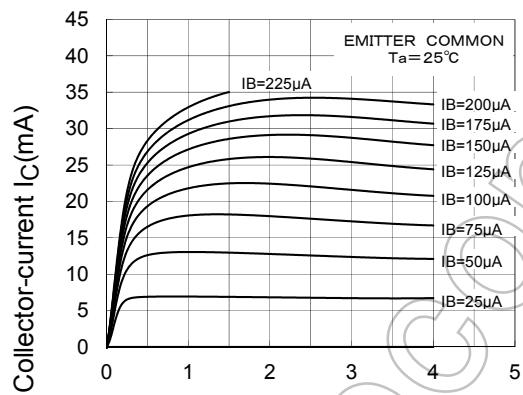
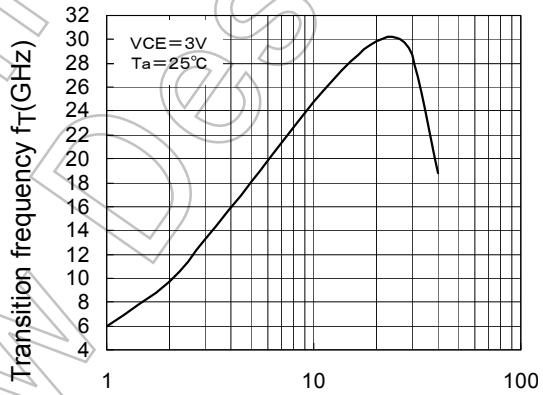
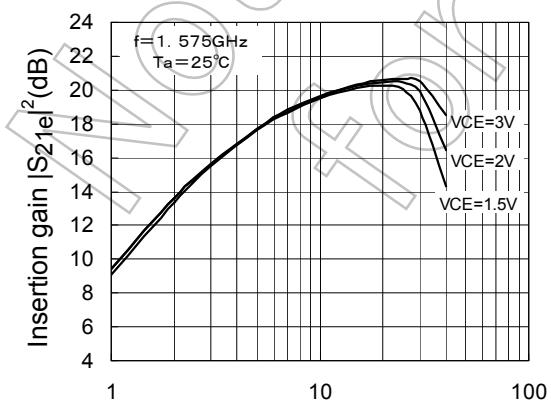
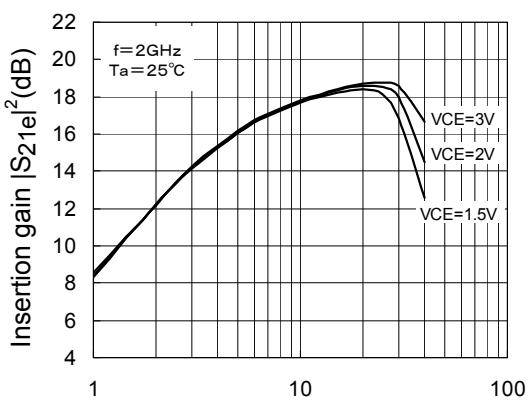
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector Cut-off Current	I _{CB0}	V _{CB} =5V, I _E =0	—	—	0.1	μA
DC Current Gain	h _{FE}	V _{CE} =3V, I _C =5mA	200	—	400	-
Reverse Transfer Capacitance	C _{re}	V _{CB} =1V, I _E =0, f=1MHz (Note3)	—	0.09	0.17	pF

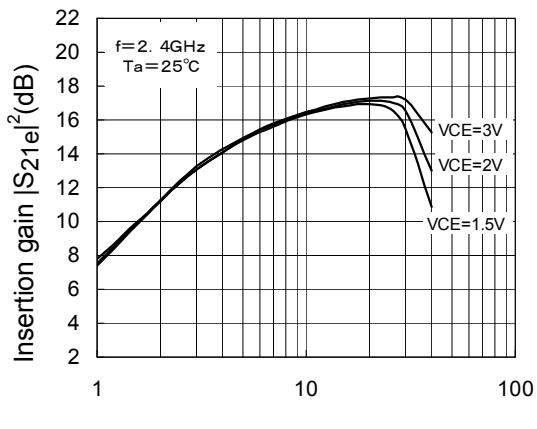
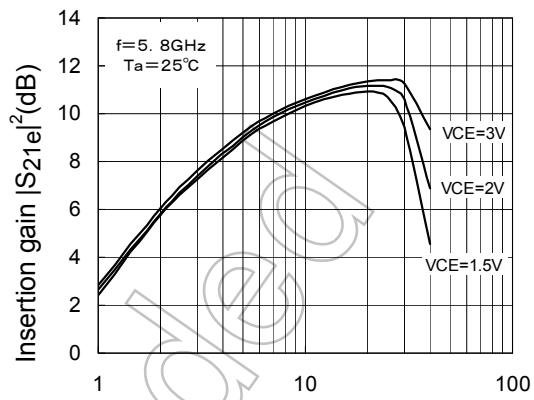
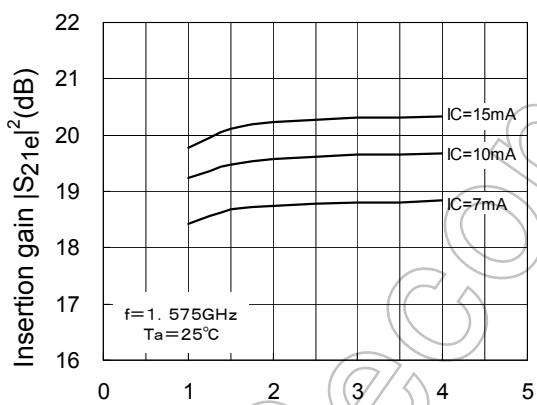
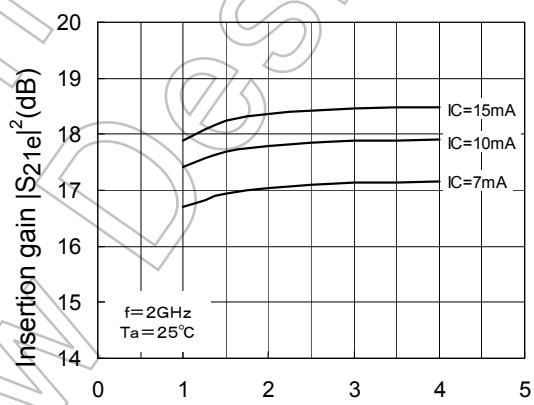
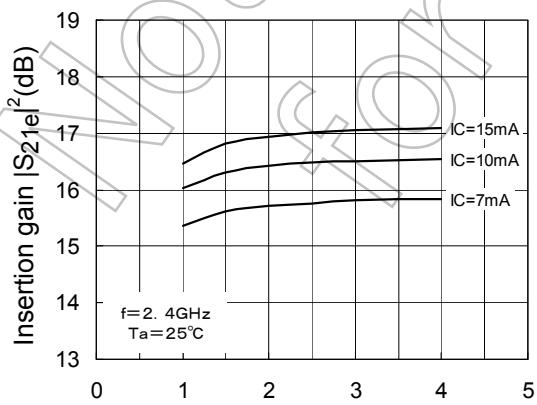
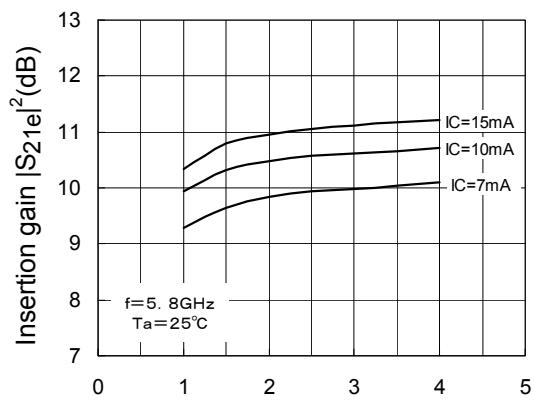
Note3: C_{re} is measured by 3 terminal method with capacitance bridge.

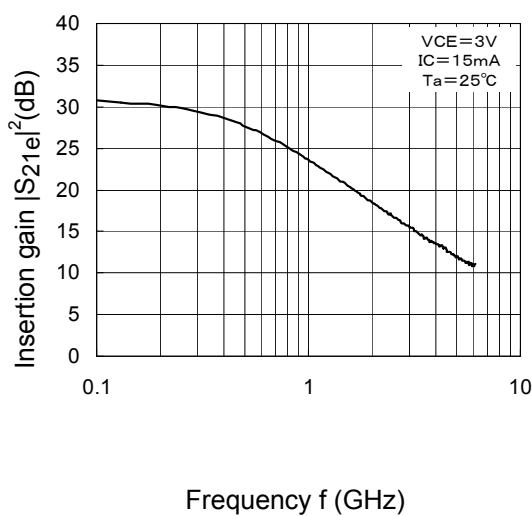
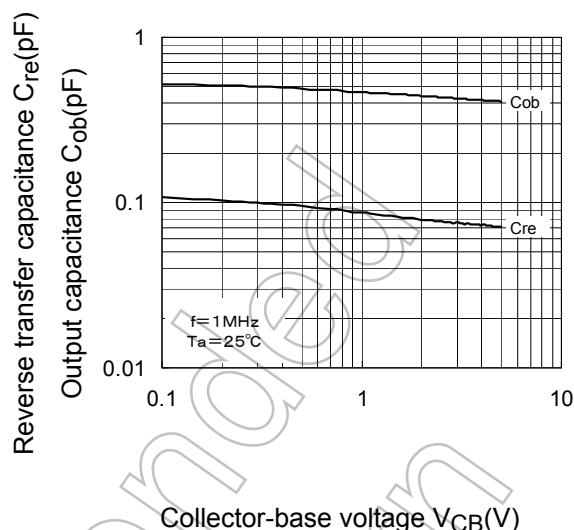
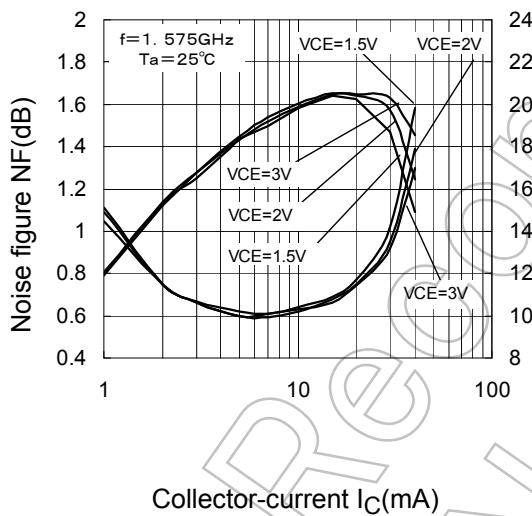
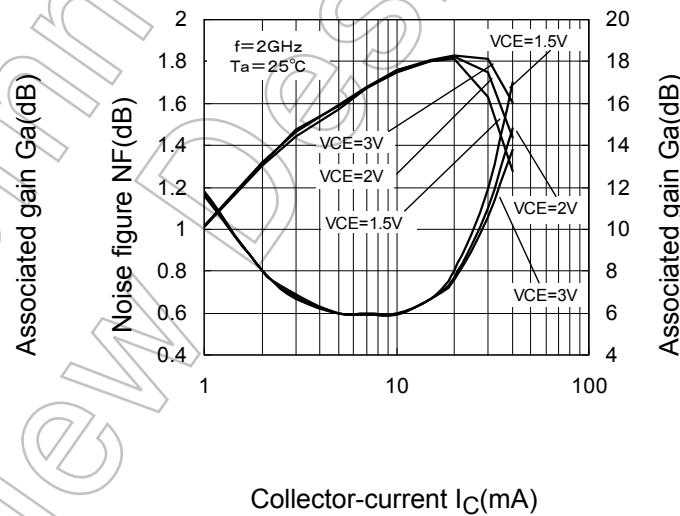
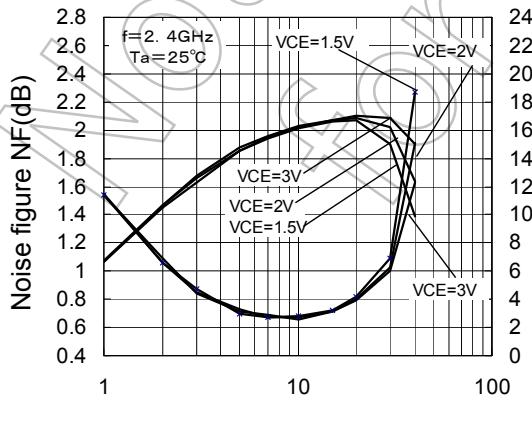
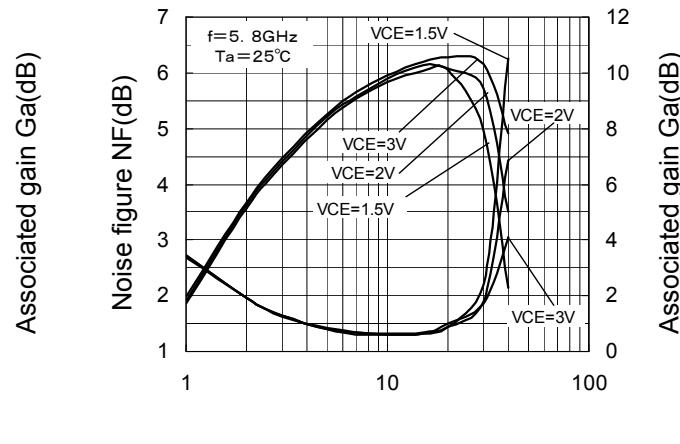
Caution:

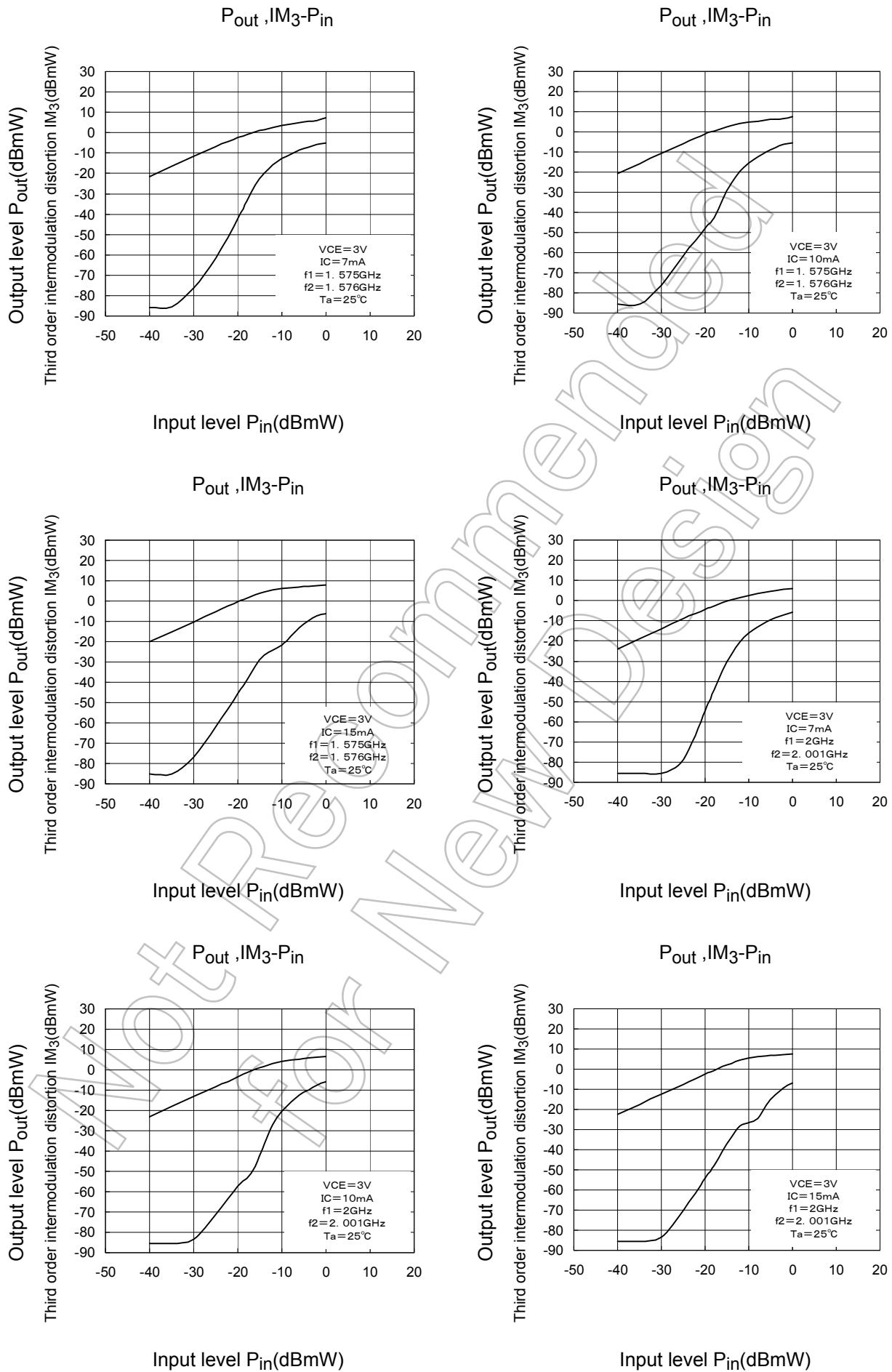
This device is due to applied the high frequency transistor process of f_T=100GHz class is used for this product.

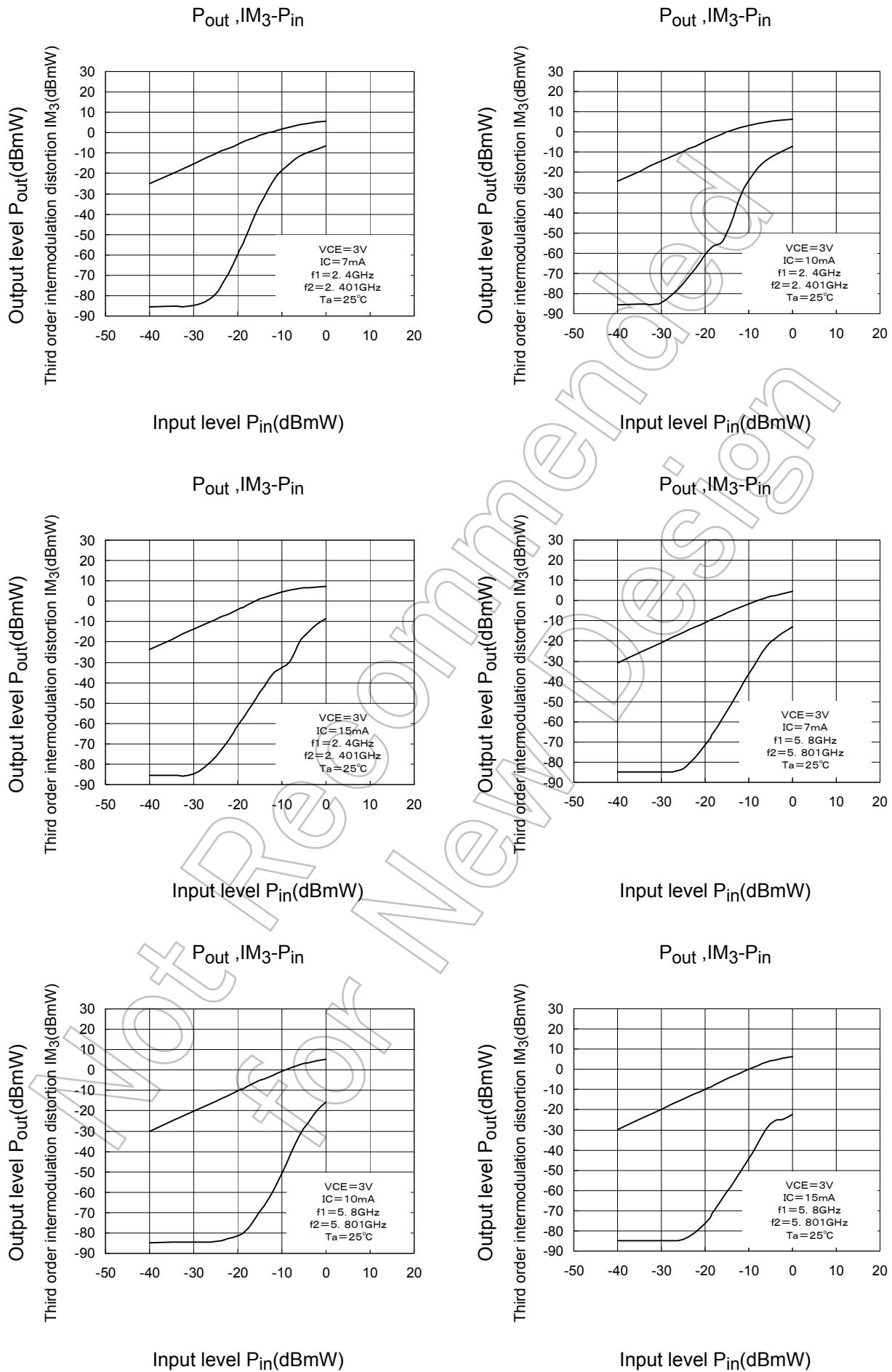
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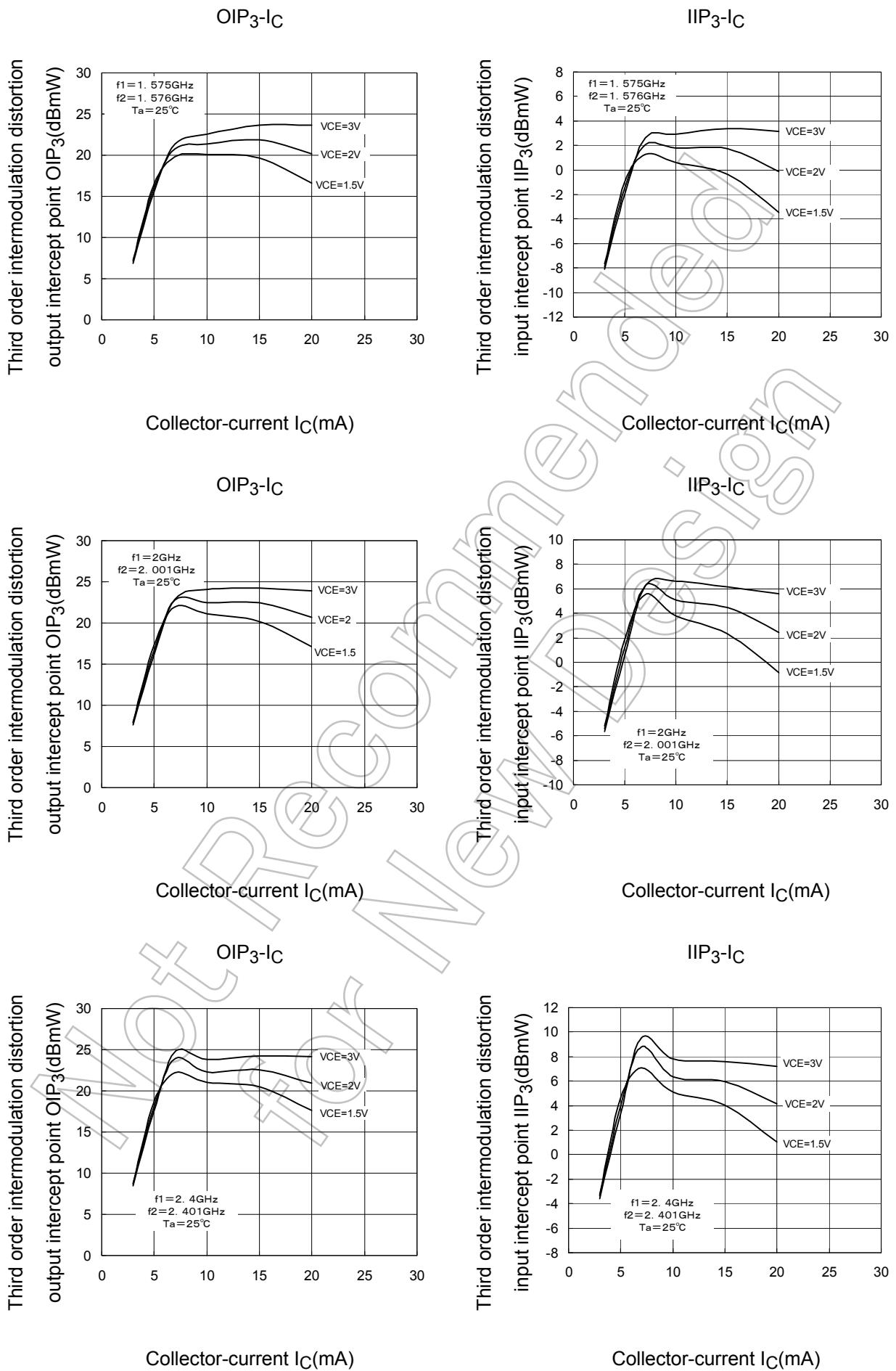
h_{FE} - I_C  I_C - V_{BE} Collector-current I_C (mA) I_C - V_{CE} Base-emitter voltage V_{BE} (V) f_T - I_C Collector-emitter voltage V_{CE} (V)Collector-current I_C (mA) $|S_{21e}|^2$ - I_C  $|S_{21e}|^2$ - I_C Collector-current I_C (mA)Collector-current I_C (mA)

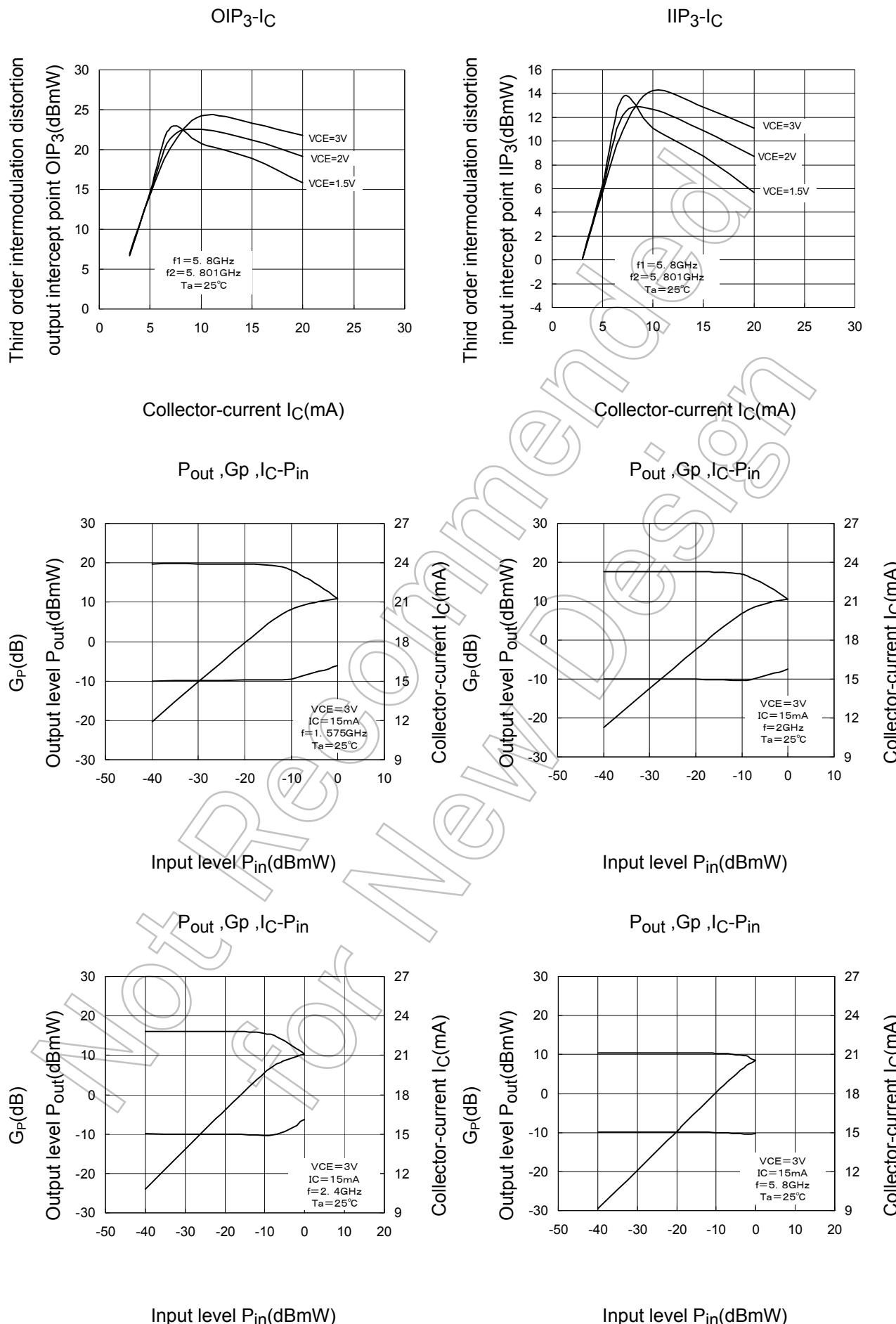
$|S_{21el}|^2 - I_C$  $|S_{21el}|^2 - I_C$  $|S_{21el}|^2 - V_{CE}$  $|S_{21el}|^2 - V_{CE}$  $|S_{21el}|^2 - V_{CE}$  $|S_{21el}|^2 - V_{CE}$ 

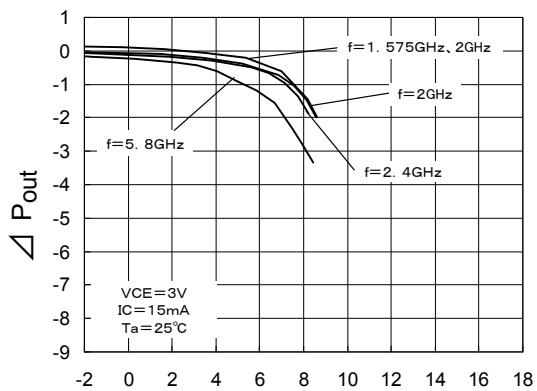
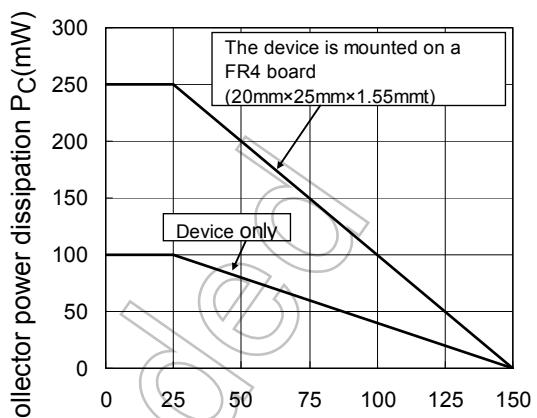
$|S_{21e}|^2 - f$  $C_{re}, C_{ob}-V_{CB}$ NF ,Ga- I_C NF ,Ga- I_C NF ,Ga- I_C NF ,Ga- I_C 









$\Delta P_{out}-P_{out}$ Output level P_{out} (dBmW) P_C-T_a Ambient temperature T_a ($^\circ\text{C}$)

Note4: The graphs indicate nominal characteristics.

Not Recommended for New Design

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